# Surface Mount Schottky Power Rectifier

**SMA Power Surface Mount Package** 

# MBRA160, NRVBA160, NRVBA160N

This device employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State of the art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity diodes in surface mount applications where compact size and weight are critical to the system.

#### Features

- Small Compact Surface Mountable Package with J-Bent Leads
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- Very Low Forward Voltage Drop
- Guard-ring for Stress Protection
- NRVBA Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable\*
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Mechanical Characteristics:**

- Case: Epoxy, Molded
- Weight: 70 mg (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 12 mm tape, 5000 units per 13 inch reel
- Polarity: Cathode Lead Indicated by Polarity Band
- ESD Ratings:
  - Machine Model = C
  - Human Body Model = 3B



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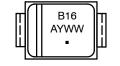
www.onsemi.com

SCHOTTKY BARRIER RECTIFIER 1.0 AMPERES 60 VOLTS



SMA CASE 403D

#### MARKING DIAGRAM



B16 = Specific Device Code

- A = Assembly Location\*\*
- ′ = Year
- WW = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

\*\*The Assembly Location code (A) is front side optional. In cases where the Assembly Location is stamped in the package bottom (molding ejecter pin), the front side assembly code may be blank.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MBRA160T3G	SMA (Pb-Free)	5,000 / Tape & Reel
NRVBA160T3G*	SMA (Pb-Free)	5,000 / Tape & Reel
NRVBA160T3G-VF01	SMA (Pb-Free)	5,000 / Tape & Reel
NRVBA160NT3G*	SMA (Pb-Free)	5,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

### MBRA160, NRVBA160, NRVBA160N

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	60	V	
Average Rectified Forward Current (At Rated V <sub>R</sub> , $T_C = 105^{\circ}C$ )	Ι <sub>Ο</sub>	1.0	A	
Average Rectified Forward Current (At Rated $V_R$ , $T_C = 70^{\circ}C$ )	Ι <sub>Ο</sub>	2.1	A	
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	60	A	
Storage/Operating Case Temperature	T <sub>stg</sub> , T <sub>C</sub>	-55 to +150	°C	
Operating Junction Temperature (Note 1)	TJ	-55 to +150	°C	
Voltage Rate of Change (Rated V <sub>R</sub> , $T_J = 25^{\circ}C$ )	dv/dt	10,000	V/µs	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. The heat generated must be less than the thermal conductivity from Junction–to–Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead (Note 2) Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JL} \ R_{ heta JA}$	35 86	°C/W

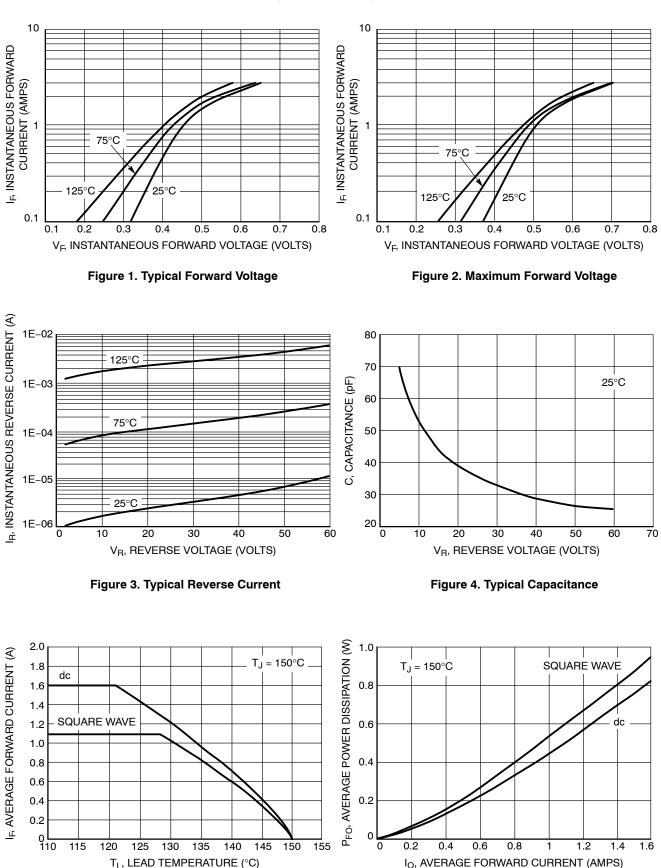
2. Mounted on 2" Square PC Board with 1" Square Total Pad Size, PC Board FR4.

#### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Value		Unit
Maximum Instantaneous Forward Voltage (Note 3)	V <sub>F</sub>	T <sub>J</sub> = 25°C	T <sub>J</sub> = 125°C	V
(I <sub>F</sub> = 1.0 A)		0.510	0.475	
Maximum Instantaneous Reverse Current	IR	$T_J = 25^{\circ}C$	T <sub>J</sub> = 125°C	mA
(V <sub>R</sub> = 60 V)		0.2	20	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: Pulse Width  $\leq$  250 µs, Duty Cycle  $\leq$  2.0%.

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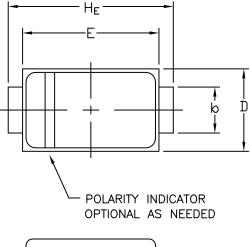


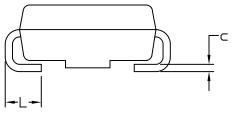
#### **MECHANICAL CASE OUTLINE** PACKAGE DIMENSIONS

# onsemi



STYLE 1 STYLE 2 SCALE 1:1

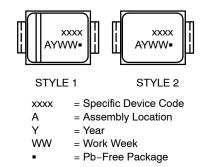




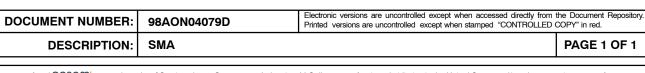


A1

#### GENERIC **MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



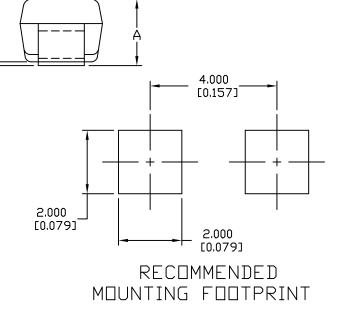
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DATE 22 OCT 2021

#### NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCHES
- DIMENSION & SHALL BE MEASURED WITHIN DIMENSION L. З.

	MILLIMETERS					
DIM	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.
A	1.97	2.10	2.20	0.078	0.083	0.087
A1	0.05	0.10	0.20	0.002	0.004	0.008
b	1.27	1.45	1.63	0.050	0.057	0.064
с	0.15	0.28	0.41	0.006	0.011	0.016
D	2.29	2.60	2.92	0.090	0.103	0.115
E	4.06	4.32	4.57	0.160	0.170	0.180
HE	4.83	5.21	5.59	0.190	0.205	0.220
L	0.76	1.14	1.52	0.030	0.045	0.060



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